F Fuji Electric 6MBI450V-120-50

IGBT Modules

IGBT MODULE (V series) 1200V / 450A / 6 in one package

Features

Compact Package P.C.Board Mount Low VCE (sat) **RoHS** Compliant product

Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply Industrial machines, such as welding machines



Maximum Ratings and Characteristics

Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items		Symbols	Conditions	Conditions		Units
		VCES			1200	V
		V _{GES}			±20	V
_			Continuous	Tc=25°C	600	
rter		Ic	Continuous	Tc=100°C	450	
Collector current		Ic pulse	1ms	1ms		А
-		-lc			450	
			1ms		900	
Collector power dissipation		Pc	1 device	1 device		W
Junction temper	ature	Tj			175	
Operation temperature (under switching conditions)		T _{jop}			150	°C
Case temperature		Tc			125	
Storage temperature		Tstg			-40 to +125	
Isolation voltage	between terminal and copper base (*1)	Viso			2500	VAC
	between thermistor and others (*2)	Viso	AC . IMIN.	AC : 1min.		
Screw torque	Mounting (*3)	-			3.5	Nm
	Terminals (*4)	-			4.5	N m

Note *1: All terminals should be connected together during the test.

Note *2: Two therminals should be connected together, other terminals should be connected together and shorted to base plate during the test. Note *3: Recommendable value : 2.5-3.5 Nm (M5) Note *4: Recommendable value : 3.5-4.5 Nm (M6)

• Electrical characteristics (at Tj= 25°C unless otherwise specified)

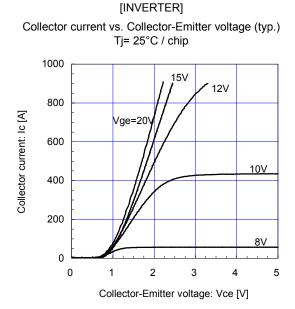
	Sumple also	Conditions		Characteristics			
ems	Symbols			min.	typ.	max.	Units
Zero gate voltage collector current	Ices	V _{GE} = 0V, V _{CE} = 1200V		-	-	3.0	mA
Gate-Emitter leakage current	Iges	$V_{GE} = 0V, V_{GE} = \pm 20V$		-	-	600	nA
Gate-Emitter threshold voltage	shold voltage V _{GE (th)} V _{CE} = 20V, I _C = 450mA			6.0	6.5	7.0	V
	V _{CE (sat)} (terminal)	V _{GE} = 15V Ic = 450A	Tj=25°C	-	2.30	2.75	v
			Tj=125°C	-	2.60	-	
			Tj=150°C	-	2.65	-	
Collector-Emitter saturation voltage	V _{CE (sat)} (chip)	V _{GE} = 15V Ic = 450A	Tj=25°C	-	1.75	2.20	
			Tj=125°C	-	2.05	-	
			Tj=150°C	-	2.10	-	
Internal gate resistance	R _{G(int)}	- V _{CE} = 10V, V _{GE} = 0V, f = 1MHz		-	1.67	-	Ω
Input capacitance	Cies			-	41	-	nF
	ton		-	550	-	nsec	
Input capacitance Turn-on time	tr	−V _{cc} = 600V Ic = 450A	-	180	-		
	tr (i)	$V_{GE} = \pm 15V$	-	120	-		
	toff	$R_{\rm G} = 0.52\Omega$	-	1050	-		
Turn-off time	tr	Ls = 80nH	-	110	-		
	V⊧ (terminal)		Tj=25°C	-	2.25	2.70	V
		V _{GE} = 0V I _F = 450A	Tj=125°C	-	2.40	-	
			Tj=150°C	-	2.35	-	
Forward on voltage	V⊧ (chip)	$V_{GE} = 0V$ IF = 450A	Tj=25°C	-	1.70	2.15	
			Tj=125°C	-	1.85	-	
			Tj=150°C	-	1.80	-	
Reverse recovery time	trr	I _F = 450A		-	200	-	nse
Desistance	P	T = 25°C		-	5000	-	- Ω
Resistance B value	R	T = 100°C		465	495	520	
B value	В	T = 25 / 50°C		3305	3375	3450	K

• Thermal resistance characteristics

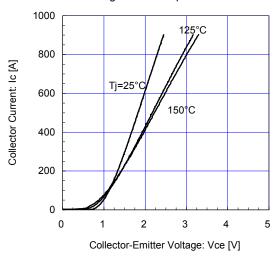
Items	Symbols	Conditions	Characteristics			Units	
	Symbols	Conditions	min.	typ.	max.	Units	
Thermal resistance (1device)	R _{th(j-c)}	Inverter IGBT	-	-	0.066		
mermanesistance (ruevice)		Inverter FWD	-	-	0.100	°C/W	
Contact thermal resistance (1device) (*5) Rth		with Thermal Compound	-	0.0167	-		

Note *5: This is the value which is defined mounting on the additional cooling fin with thermal compound.

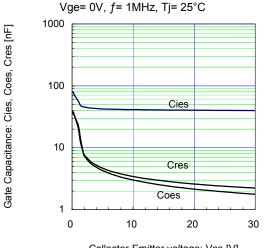
Characteristics (Representative)

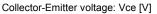


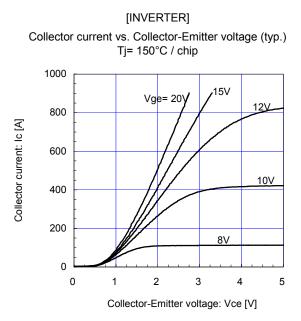




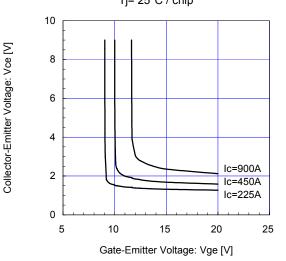
[INVERTER] Gate Capacitance vs. Collector-Emitter Voltage (typ.)





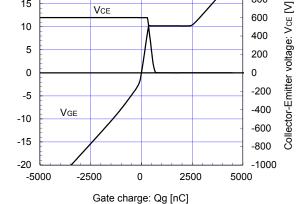


[INVERTER] Collector-Emitter voltage vs. Gate-Emitter voltage (typ.) Tj= 25°C / chip

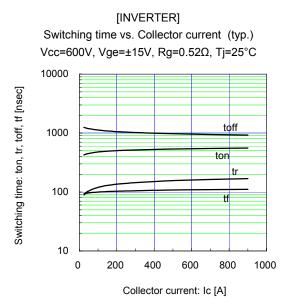


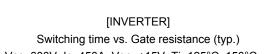
[INVERTER]

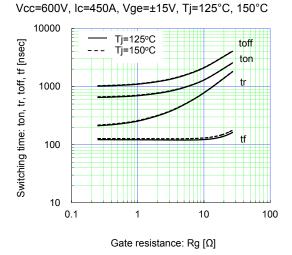
Dynamic Gate Charge (typ.) Vcc=600V, Ic=450A, Tj= 25°C 1000 20 800 15 VCE 600



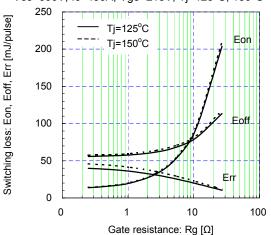
Gate-Emitter voltage: VGE [V]







[INVERTER] Switching loss vs. Gate resistance (typ.) Vcc=600V, Ic=450A, Vge=±15V, Tj=125°C, 150°C

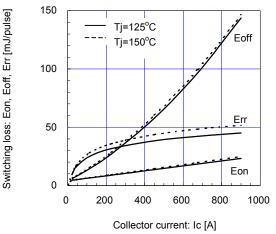


Switching time vs. Collector current (typ.) Vcc=600V, Vge=±15V, Rg=0.52Ω, Tj=125°C, 150°C 10000 Tj=125°C Switching time: ton, tr, toff, tf [nsec] Tj=150°C toff 1000 ton tr tf 100 10 0 200 400 600 800 1000

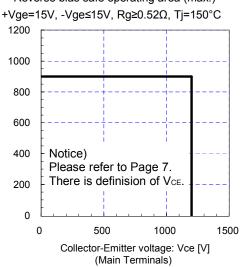
[INVERTER]

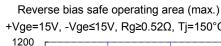
Collector current: Ic [A]

[INVERTER] Switching loss vs. Collector current (typ.) Vcc=600V Vge=±15V, Rg=0.52Ω, Tj=125°C, 150°C

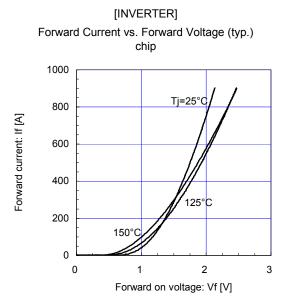


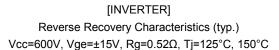
[INVERTER]

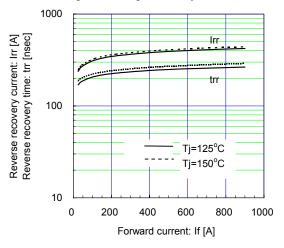




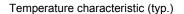
Collector current: Ic [A]

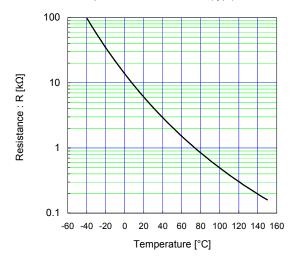


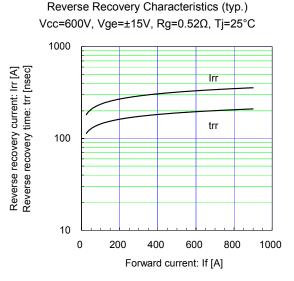




[THERMISTOR]

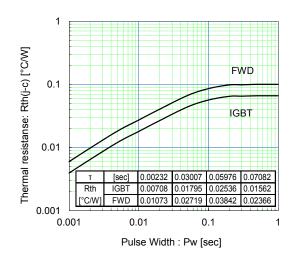




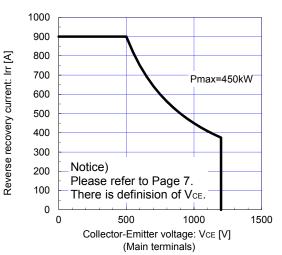


[INVERTER]

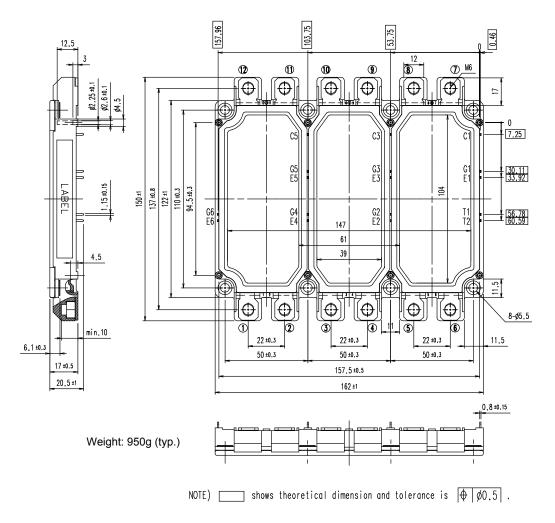
Transient Thermal Resistance (max.)



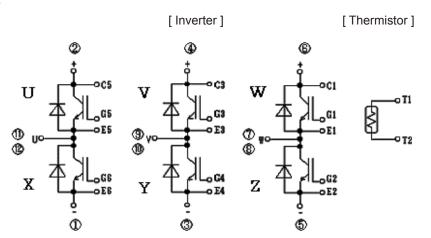
FWD safe operating area (max.) Tj=150°C



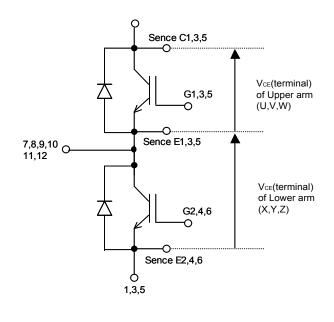
■ Outline Drawings(Unit:mm)



Equivalent Circuit



Definition of switching characteristics



Switching characteristics of V_{CE} is defined between Sense C1,3,5 and Sense E1,3,5 for Upper arm(U,V,W) and Sense E1,3,5 and Sense E2,4,6 for Lower arm(X,Y,Z).

Please use these terminals whenever measure spike voltage.

WARNING

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